

====== WPI ======

TI - Coating for yttrium silicate film formed on silicon carbide - involves coating oxides of boron, zinc, sodium and iron and heat treating

AB - JP11278968 NOVELTY - Any one or two of B203, ZnO, Na2CO3 and Fe2O3 are mixed and coated over surface of Y2SiO5 and heat treated.

- USE - For yttrium silicate film formed on silicon carbide.

- ADVANTAGE - Improves oxidation resistance of silicon carbide.

- (Dwg.0/5)

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PA - (MITO) MITSUBISHI JUKOGYO KK

MC - L02-G12 L02-J02C

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IC - B01J19/00 ;C04B41/87 ;C04B41/89

AN - 1999-629172 [54]

PAJ ======

TI - METHOD FOR IMPROVING AIR-TIGHTNESS OF DIVITRIUM SILICON PENTOXIDE COATING FILM

AB - PROBLEM TO BE SOLVED: To increase the air-tightness of a Y2 SiO5 coating film and completely prevent the oxygen attack on the surface of a part from outer environment by coating a surface of a Y2 SiO5 coating film with an oxide composed of B2 O3 , ZnO, Na2 CO3 or Fe2 O3 or their arbitrary mixture and heat-treating the coated product.

- SOLUTION: The surface of a Y2 SiO5 coating film formed on the surface of a part is coated with B2 O3 , ZnO, Na2 CO3 or Fe2 O3 or their arbitrary mixture and heat-treated at 1573-1973 K for 1-100 hr to increase the air-tightness of the Y2 SiO5 coating film. The oxide to be applied to the surface of Y2 SiO5 may be incorporated with <=70 mol.% of Y2 O3 , SiO2 or their mixture. The applied oxide is introduced into the open pare of the Y2 SiO5 coating film to close the open pore and remarkably improve the air-tightness of the Y2 SiO5 coating film. Accordingly, the oxygen attack on the surface of the part from outer environment is sufficiently prevented to get a satisfiable oxidation inhibiting effect.

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